

# Albert Polman

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data 27-2-2010

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6. *Ultrasmall mode volume plasmonic nanodisk resonators*  
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7. *Field enhancement in metallic subwavelength aperture arrays probed by erbium upconversion luminescence*  
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8. *Modal decomposition of surface-plasmon whispering gallery resonators*  
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14. *Nanowire plasmon excitation by adiabatic mode transformation*  
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16. *Fabry-Pérot resonators for surface plasmon polaritons probed by cathodoluminescence*  
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